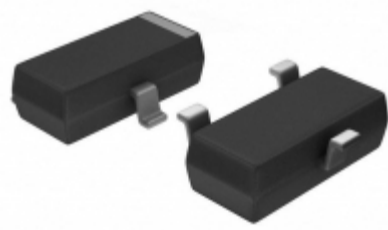
	<h2 style="color: red;">FJV4103RMTF</h2>
	<p>Hersteller-Teilenummer: FJV4103RMTF</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: TRANS PREBIAS PNP 200MW SOT23-3</p> <p>Datenblätter: 1.FJV4103RMTF.pdf 2.FJV4103RMTF.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 357619 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FJV4103RMTF
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PREBIAS PNP 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	357619 pcs Stock
detaillierte Beschreibung	Pre-Biased Bipolar Transistor (BJT) PNP - Pre-Biased
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	PNP - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 500µA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	56 @ 5mA, 5V
Frequenz - Übergang	200MHz
Verpackung	Tape & Reel (TR)
Widerstand - Basis (R1)	22 kOhms
Widerstand - Emitterbasis (R2)	22 kOhms
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FJV4103RMTF ist neu im Original, Suche FJV4103RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV4103RMTF AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV4103RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FJV4106RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4105RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4102RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4104RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>
 <p>FJV4103RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4104RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4102RLIMTF FAI FJV4102RLIMTF FAI</p>	 <p>FJV4102RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>

heiße Teile

Mehr

⊗ FJV3106RMTF	↔ FJV3107RMTF	⇒ FJV3107RMTF	D FJV3108RMTF	⇒ FJV3108RMTF
⊣ FJV3109R	⊗ FJV3109RMTF	D FJV3109RMTF	⇒ FJV3110RMTF	⇒ FJV3110RMTF
⊗ FJV3111RMTF	⊣ FJV3111RMTF	⊗ FJV3112RMTF	↔ FJV3112RMTF	⇒ FJV3113RMTF
D FJV3113RMTF	⊗ FJV3114RMTF	⊣ FJV3114RMTF	⊗ FJV3115RMTF	⇒ FJV3115RMTF
⇒ FJV4101RMTF	↔ FJV4101RMTF	⊗ FJV4102RLIMTF	⊣ FJV4102RMTF	⇒ FJV4102RMTF
↔ FJV4103RMTF	⇒ FJV4104RMTF	D FJV4104RMTF	⊗ FJV4105RMTF	⊣ FJV4105RMTF
⊗ FJV4106RMTF	D FJV4106RMTF	⇒ FJV4107RMTF	↔ FJV4107RMTF	⇒ FJV4108RMTF
⊣ FJV4108RMTF	⊗ FJV4109RMTF	↔ FJV4109RMTF	⇒ FJV4110RMTF	⇒ FJV4110RMTF
⊗ FJV4111RMTF	⊣ FJV4111RMTF	⊗ FJV4112RMTF	D FJV4112RMTF	⇒ FJV4113RMTF
↔ FJV4113RMTF	⊗ FJV4114RMTF	⊣ FJV4114RMTF	⊗ FJV42MTF	⇒ FJV42MTF

Contact us: Info@Y-IC.com

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